## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1968	((438/190) or (438/210) or (438/238) or (438/382)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 15:49
L2	716	1 and (first and second) with (dop\$4 implant\$5)	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:50
L3	156	2 and (first with (dop\$4 implant\$5) with transistor)	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 15:51
L4	317	2 and (first with (dop\$4 implant\$5) with (transistor gate))	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:50
L5	65	4 and (second with (dop\$4 implant\$5) with (resistor resistive))	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:50
L6	152	((257/e27.016) or (257/e27.03) or (257/e27.033) or (257/e27.045)). CCLS.	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/03/14 15:59
L7	6	6 and (first and second) with (dop\$4 implant\$5)	FPRS; EPO; JPO; DERWENT; IBM_TDB	OR.	OFF	2007/03/14 16:49
L8	32608	(transistor and resistor).clm.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:49
L9	42523	((transistor gate) and (resistor resistive)).clm.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:50
L10	960	9 and ((first and second) with (dop\$4 implant\$5)).clm.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:50
L11	481	10 and ((first with (dop\$4 implant\$5) with (transistor gate))).clm.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:50
·L12	204	11 and ((second with (dop\$4 implant\$5) with (resistor resistive))). clm.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:51
L13	13	12 and (((field with oxide) fox isolation) with (well tub)).clm.	US-PGPUB; USPAT; USOCR	OR	OFF	2007/03/14 16:52